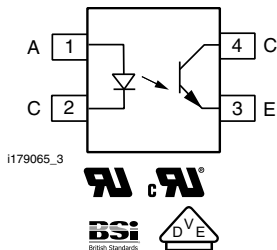




Optocoupler Phototransistor Output, SOP-4, 100 mil Pitch, Mini-Flat Package



1179066



FEATURES

- SOP (small outline package)
- Isolation test voltage, 3750 V_{RMS} (1 s)
- High collector emitter breakdown voltage, V_{CEO} = 70 V
- Low saturation voltage
- Fast switching times
- Temperature stable
- Low coupling capacitance
- End-stackable, 0.100" (2.54 mm) spacing
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912



DESCRIPTION

The SFH690ABT, SFH690AT, SFH690BT, SFH690CT, SFH690DT family has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin 100 mil lead pitch miniflat package. It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling devices are designed for signal transmission between two electrically separated circuits. The SFH690 series is available only on tape and reel. There are 2000 parts per reel. Marking for SFH690AT is 690A; SFH690BT is 690B; SFH690CT is 690C; SFH690DT is 690D; SFH690ABT will be marked as 690A or 690B.

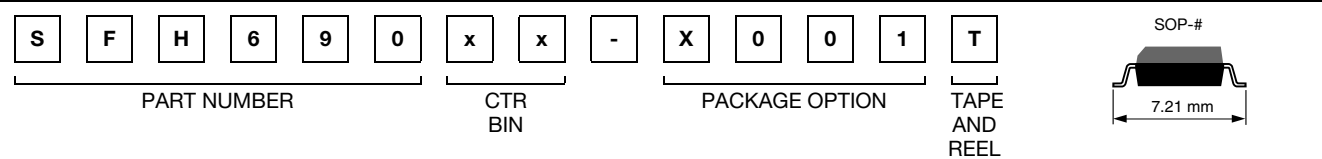
APPLICATIONS

- High density mounting or space sensitive PCBs
- PLCs
- Telecommunication

AGENCY APPROVALS

- UL1577, file no. E52744 system code U
- cUL tested to CSA 22.2 bulletin 5A
- BSI IEC 60950; IEC 60065
- DIN EN 60747-5-2 (VDE 0884) available with option 1

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)				
UL, cUL, BSI	50 to 300	50 to 150	100 to 300	100 to 200	200 to 400
SOP-4, 100 mil pitch	SFH690ABT	SFH690AT ⁽¹⁾ , SFH690AT ⁽²⁾	SFH690BT ⁽¹⁾ , SFH690BT ⁽²⁾	SFH690CT	SFH690DT
VDE, UL, cUL, BSI	50 to 300	50 to 150	100 to 300	100 to 200	200 to 400
SOP-4, 100 mil pitch	-	-	SFH690B-X001T	SFH690C-X001T	SFH690D-X001T

Notes

- (1) Product is rotated 180° in tape and reel cavity
- (2) Also available in tubes, do not put "T" to the end



ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
DC forward current		I_F	50	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	2.5	A
Power dissipation		P_{diss}	80	mW
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
	$t_p \leq 1\text{ ms}$	I_C	100	mA
Power dissipation		P_{diss}	150	mW
COUPLER				
Isolation test voltage between emitter and detector (1 s)		V_{ISO}	3750	V_{RMS}
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 55 to + 100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	max. 10 s dip soldering distance to seating plane $\geq 1.5\text{ mm}$	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽³⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

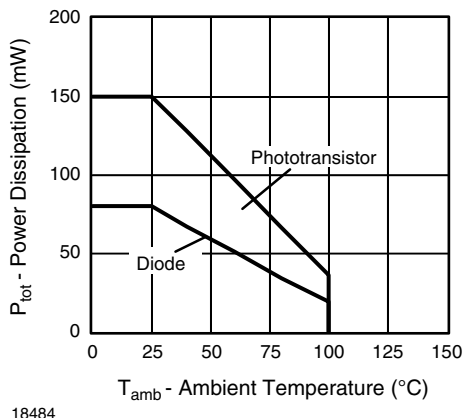


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature



ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	I _F = 5 mA	V _F		1.15	1.4	V
Reverse current	V _R = 6 V	I _R		0.01	10	μA
Capacitance	V _R = 0 V, f = 1 MHz	C _O		14		pF
Thermal resistance		R _{thJA}		750		K/W
OUTPUT						
Collector emitter leakage current	V _{CE} = 20 V	I _{CEO}			100	nA
Collector emitter capacitance	V _{CE} = 5 V, f = 1 MHz	C _{CE}		2.8		pF
Thermal resistance		R _{thJA}		500		K/W
COUPLER						
Collector emitter saturation voltage	I _F = 10 mA, I _C = 2 mA	V _{CEsat}		0.1	0.3	V
Coupling capacitance	f = 1 MHz	C _C		0.3		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	I _F = 5 mA, V _{CE} = 5 V	SFH690ABT	CTR	50		300	%
		SFH690AT	CTR	50		150	%
		SFH690BT	CTR	100		300	%
		SFH690CT	CTR	100		200	%
		SFH690DT	CTR	200		400	%

SWITCHING CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	I _C = 2 mA, V _{CC} = 5 V, R _L = 100 Ω	t _r		3		μs
Fall time	I _C = 2 mA, V _{CC} = 5 V, R _L = 100 Ω	t _f		4		μs
Turn-on time	I _C = 2 mA, V _{CC} = 5 V, R _L = 100 Ω	t _{on}		5		μs
Turn-off time	I _C = 2 mA, V _{CC} = 5 V, R _L = 100 Ω	t _{off}		3		μs

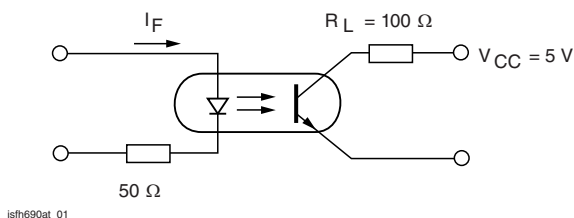


Fig. 2 - Switching Operation (without Saturation)



SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}			6000			V
V_{IORM}			707			V
P_{SO}					350	mW
I_{SI}					150	mA
T_{SI}					175	°C
Creepage distance			5			mm
Clearance distance			5			mm
Insulation thickness			0.4			mm

Note

- As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)

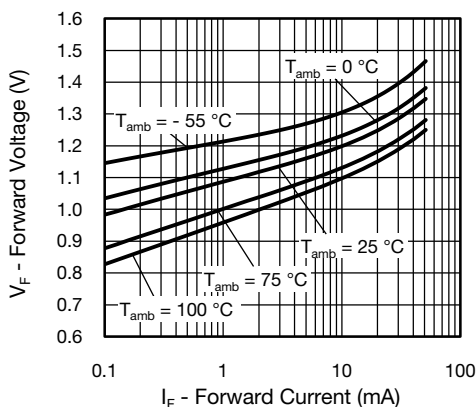


Fig. 3 - Forward Voltage vs. Forward Current

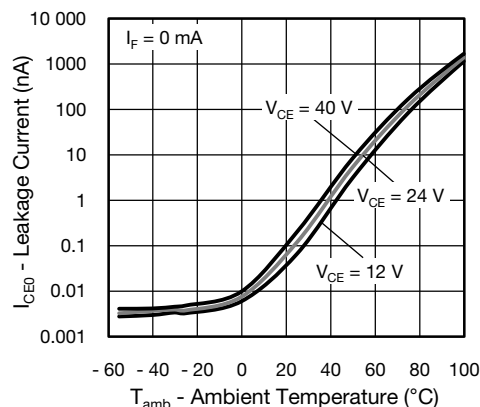


Fig. 5 - Leakage Current vs. Ambient Temperature

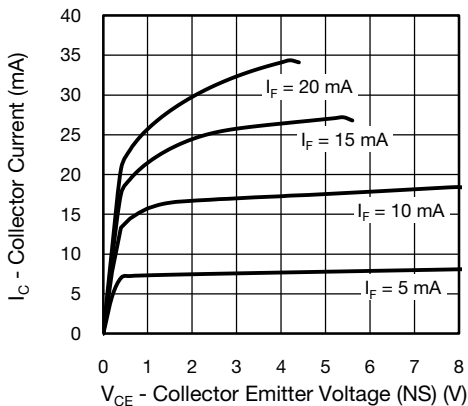


Fig. 4 - Collector Current vs. Collector Emitter Voltage (NS)

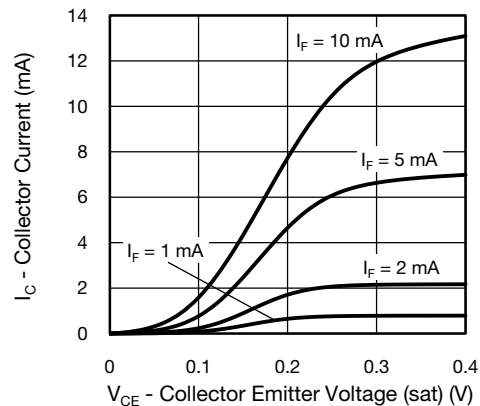


Fig. 6 - Collector Current vs. Collector Emitter Voltage (sat)

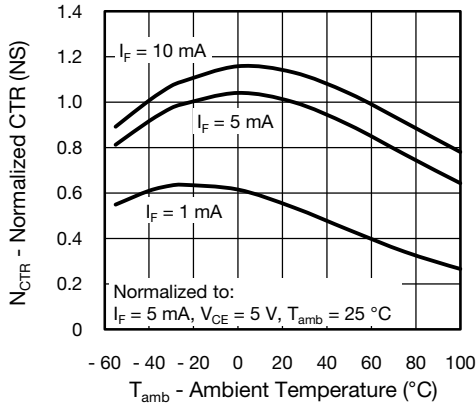


Fig. 7 - Normalized Current Transfer Ratio (sat) vs. Ambient Temperature

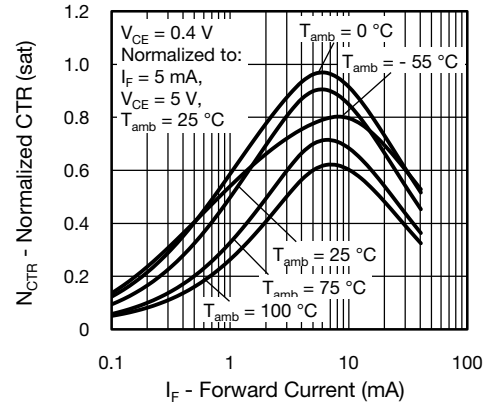


Fig. 10 - Normalized CTR (sat) vs. Forward Current

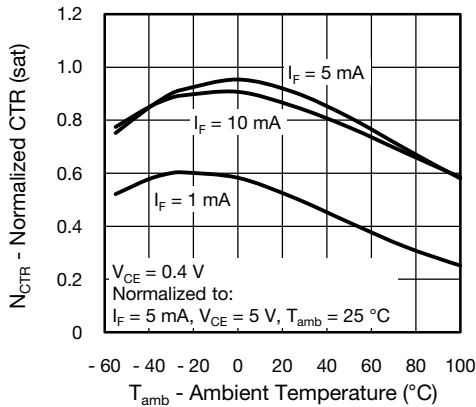


Fig. 8 - Normalized Current Transfer Ratio (NS) vs. Ambient Temperature

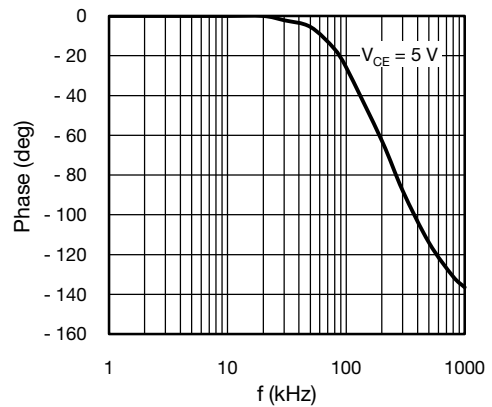


Fig. 11 - F_{CTR} vs. Phase Angle

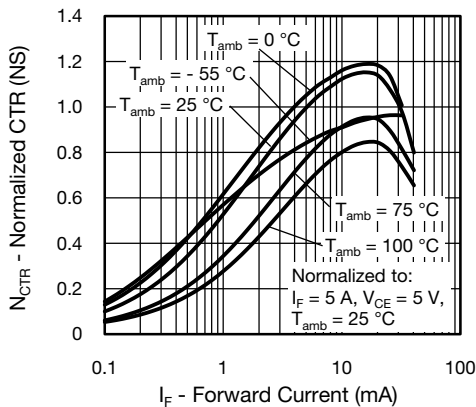


Fig. 9 - Normalized CTR (NS) vs. Forward Current

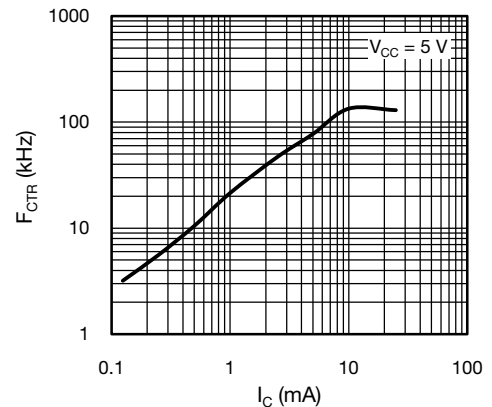


Fig. 12 - F_{CTR} vs. Collector Current



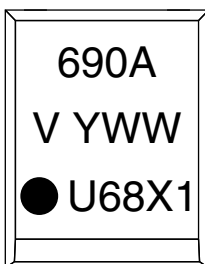
Fig. 13 - Switching Time vs. Load Resistance

PACKAGE DIMENSIONS in millimeters



i178037

PACKAGE MARKING (example of SFH690AT)



Notes

- Only option 1 is reflected in the package marking with the characters "X1"
- Tape and reel suffix (T) is not part of the package marking



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